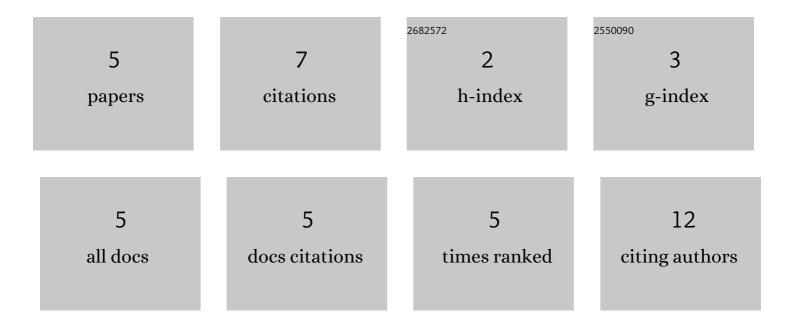


## List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/871722/publications.pdf Version: 2024-02-01



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#	Article	IF	CITATIONS
1	Optimization of driving current and crosstalk effect in epitaxial diode array for phase change memory application. Semiconductor Science and Technology, 2020, 35, 115001.	2.0	Ο
2	High performance of multilevel-cell phase change memory device with good endurance reliability. Semiconductor Science and Technology, 2019, 34, 105019.	2.0	4
3	Subsequent set pulse impacts on set resistance distribution of phase change memory. Semiconductor Science and Technology, 2019, 34, 105024.	2.0	Ο
4	Analysis and optimization of read/write reliability for 12 <i>F</i> <sup>2</sup> cross-point ultra-fast phase change memory. Semiconductor Science and Technology, 2019, 34, 115013.	2.0	2
5	First Set Pulse Impacts on Set Resistance Distribution of Phase Change Random Access Memory. ECS Journal of Solid State Science and Technology, 2019, 8, Q5-Q8.	1.8	1